

TGS 2610 - for the detection of LP Gas

Features:

- * Low power consumption
- * High sensitivity to LP and its component gases (e.g. propane and butane)
- * Long life and low cost
- * Uses simple electrical circuit

TGS2610 is a semiconductor type gas sensor which combines very high sensitivity to LP gas with low power consumption and long life. Due to miniaturization of its sensing chip, TGS2610 requires a heater current of only 56mA and the device is housed in a standard TO-5 package.

The TGS2610 is available in two different models which have different external housings but identical sensitivity to LP gas. Both models are able to satisfy the requirements of performance standards such as UL1484 and EN50194.

TGS2610-C00 possesses small size and quick gas response, making it suitable for gas leakage checkers.

TGS2610-D00 uses filter material in its housing which eliminates the influence of interference gases such as alcohol, resulting in highly selective response to LP gas. This feature makes the sensor ideal for residential gas leakage detectors which require durability and resistance against interference gas.



Applications:

- * Portable LP detectors
- * LP gas and vapor detection



The figure below represents typical sensitivity characteristics, all data having been gathered at standard test conditions (see reverse side of this sheet). The Y-axis is indicated as sensor resistance ratio (Rs/Ro) which is defined as follows:

Rs = Sensor resistance in displayed gases at various concentrations Ro = Sensor resistance in 1800ppm of iso-butane



TGS2610-D00 Sensitivity Characteristics:



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Basic Measuring Circuit:

The sensor requires two voltage inputs: heater voltage (V_H) and circuit voltage (V_C). The heater voltage (V_H) is applied to the integrated heater in order to maintain the sensing element at a specific temperature which is optimal for sensing. Circuit voltage (V_C) is applied to allow measurement of voltage (V_{OUT}) across a load resistor (R_L) which is connected in series with the sensor.

A common power supply circuit can be used for both V_C and V_H to fulfill the sensor's electrical requirements. The value of the load resistor (R_L) should be chosen to optimize the alarm threshold value, keeping power dissipation (Ps) of the semiconductor below a limit of 15mW. Power dissipation (Ps) will be highest when the value of Rs is equal to R_L on exposure to gas.



Specifications:

Model number		TGS2610		
Sensing principle		MOS type		
Standard package		TO-5 metal can		
Target gases		Butane, LP gas		
Typical detection range		500 ~ 10,000ppm		
Heater voltage	Vн	5.0±0.2V AC/DC		
Circuit voltage	Vc	5.0±0.2V DC	Ps≤15mW	
Load resistance	RL	variable	0.45kΩ min.	
Heater resistance	Rн	approx 59Ω at room temp.		
Heater current	Ін	56±5mA		
Heater power consumption	Рн	280mW	VH=5.0V DC	
Sensor resistance	Rs	0.68~6.8kΩ in 1800ppm iso-butane		
Sensitivity (change ratio of Rs)		0.56±0.06	Rs (3000ppm) Rs (1000ppm)	
Test gas conditions		lso-butane in air at 20±2°C, 65±5%RH		
Circuit conditions	rcuit conditions		Vc = 5.0±0.01V DC VH = 5.0±0.05V DC	
Conditioning period before test		7 days		
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Structure and Dimensions:



The value of power dissipation (Ps) can be calculated by utilizing the following formula:

$$Ps = \frac{(V_{C} - V_{RL})^2}{Rs}$$

Sensor resistance (Rs) is calculated with a measured value of VOUT(VRL) by using the following formula:

Pin connection:

- 1: Heater
 - 2: Sensor electrode (-) 3: Sensor electrode (+)
 - 4: Heater

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